

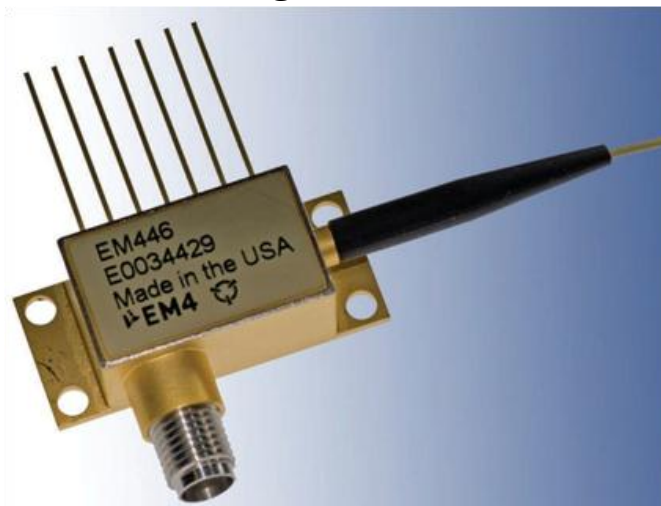
## 1310nm/1550nm CWDM High-Bandwidth Laser

### Features

- 10-18mW output power
- High bandwidth
- Built in isolator
- Ultrafast pulsing capability
- Laser welded, hermetically sealed
- Built in TEC, thermistor, and monitor detector
- Rugged to shock and vibration

### Applications

- Analog RF links
- High speed pulsing



### General Description

The AA0701 distributed feedback laser (DFB) is an InGaAsP/InP multi-quantum well laser diode. The module is ideal in applications where high bandwidth, mode stability, low RIN and stable output power are needed. AA0701 contains a thermo-electric cooler, thermistor, back facet monitor detector, and bias tee. The module is designed and built using G & H's high-reliability platform for defense components.

### Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and operation of the device at these or conditions beyond these is not implied. Exposure to absolute maximum ratings for extended periods of time may affect device reliability.

Parameter	Sym.	Condition	Min	Max	Unit
Storage Temperature	T <sub>STG</sub>		-40	+85	°C
Operating Case Temperature	T <sub>OP</sub>		-20	+70	°C
Laser Forward Current	I <sub>F</sub>			120	mA
Laser Reverse Voltage	V <sub>R</sub>			2	V
Photo Diode Photo Current	I <sub>PD</sub>			10	mA
Photo Diode Reverse Voltage	V <sub>PD</sub>			20	V
TEC Current	I <sub>TEC</sub>			3.0	A
TEC Voltage	V <sub>TEC</sub>			4.0	V
Thermistor Current				2	mA
Thermistor Voltage				5	V
Lead Soldering Time				10	s
Lead Soldering Temperature				250	°C
RF Input Power	P <sub>IN</sub>			20	dBm

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### Optical Characteristics

$T_{OP}=25^{\circ}C$ , continuous wave and beginning of life unless otherwise specified.

Parameter	Sym.	Condition	Min	Typ	Max	Unit
Operating Chip Temperature	$T_{CHIP}$		15		35	$^{\circ}C$
Center Wavelength	$\lambda$	$P=P_{OP}$	-10 -1	1310 1550 <sup>1</sup>	+10 +1	nm
Output Power (except 1310nm SMF)	$P_{OP}$	$I=I_{OP}$	10			mW
Linewidth	$\Delta \nu$	CW		1		MHz
Relative Intensity Noise	RIN	$P=P_{OP}$ , 0.2GHz $\rightarrow$ 3GHz		-150		dB/Hz
Side Mode Suppression	SMSR	$P=P_{OP}$	30			dB
Optical Isolation	ISO		30	35		dB
Polarization Extinction Ratio	PER	PM fiber option	17	19		dB
Tracking Error		$P=P_{OP}$	-0.5		0.5	dB

Note<sup>1</sup>: 1550nm standard, other center wavelengths available from 1528-1570nm. Contact factory for more information.

### Optical Fiber Specification

Parameter	Type	Unit
Fiber Type	PM/SM dependent on option	-
Connector Type	FC/APC, SC/APC, LCA, None, dependent on option	-
Buffer Diameter PM Option	250	$\mu m$
Buffer Diameter SM Option	900	$\mu m$
Buffer Material PM Option	Acrylate	-
Buffer Material SM Option	Hytrel	-
Minimum Pigtail Length	1	m
Minimum Bend Radius	35	mm

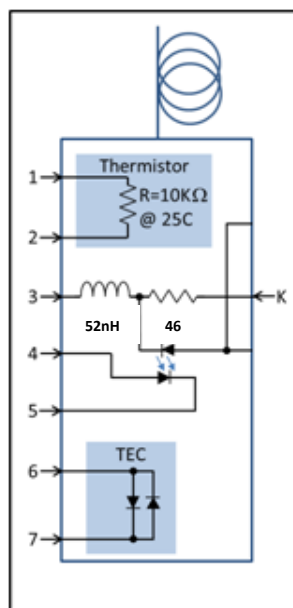
## 1310nm/1550nm CWDM High-Bandwidth Laser

### Electrical Characteristics

Parameter	Sym.	Condition	Min	Typ	Max	Unit
Threshold Current	$I_{TH}$		8		20	mA
Laser Drive Current	$I_{OP}$			75	100	mA
Laser Forward Voltage	$V_F$	$I=I_{MAX}$		1.6	2	V
Monitor Photo Diode Current	$I_{PD}$	$P=P_{OP}$	50			$\mu$ A
Monitor Photo Diode Dark Current	$I_D$				100	nA
Modulation Bandwidth	F	-3dB from low frequency average	10			GHz
Electrical Back Reflection	$S_{11}$				-10	dB
Modulation Input Matching	$Z_{IN}$			50		$\Omega$
TEC Current		$T_{OP}=70^{\circ}C, P=P_{OP}, T_{CHIP}=25^{\circ}C$			2.0	A
TEC Voltage		$T_{OP}=70^{\circ}C, P=P_{OP}, T_{CHIP}=25^{\circ}C$			2.5	V
Thermistor Resistance	$R_{TH}$	$T=25^{\circ}C$	9500	10000	10500	$\Omega$
Thermistor $\beta$ Coefficient	$\beta$	0 / 50 $^{\circ}C$		3892		
Thermistor Steinhart-Hart Coeff.	A			1.1291e-3		
	B			2.3413e-4		
	C			8.7674e-8		

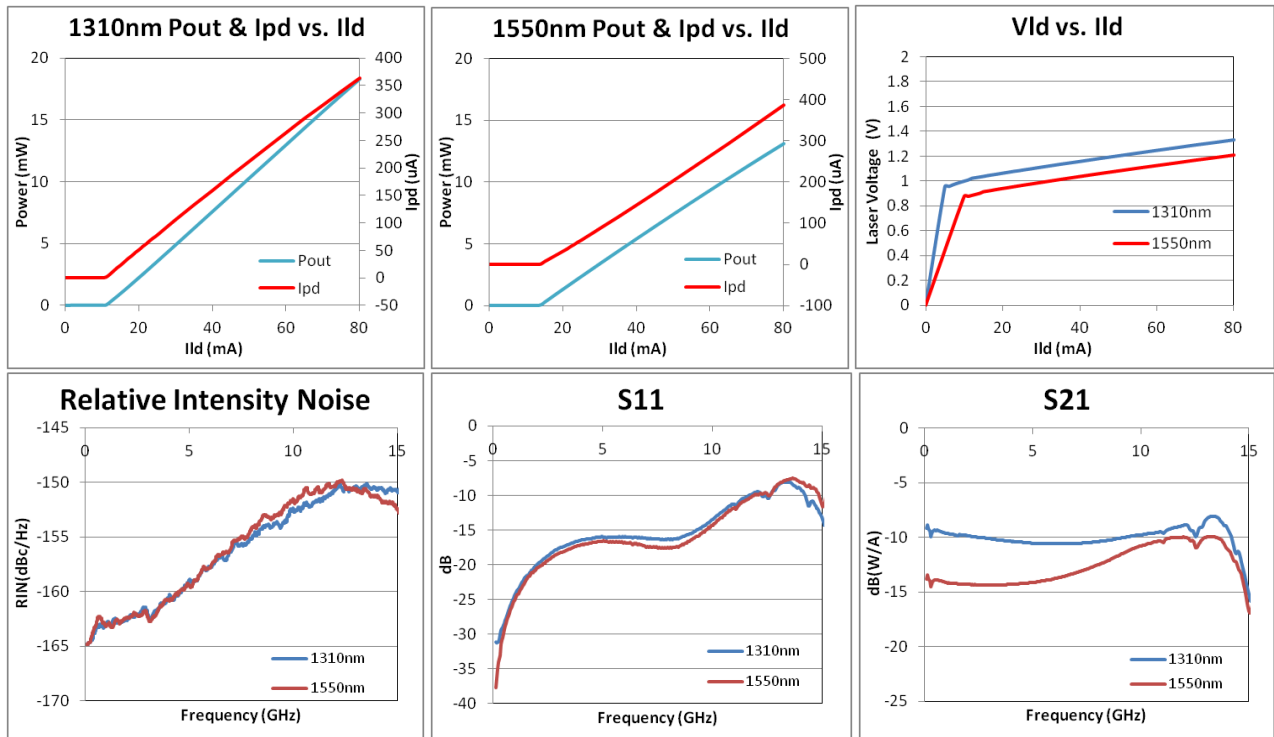
### Device Pinout

Pin	Description
1	Thermistor
2	Thermistor
3	Laser Cathode (Bias)
4	Monitor PD Anode
5	Monitor PD Cathode
6	TEC +
7	TEC -
Pkg/Shield	Laser Anode
K	RF Input



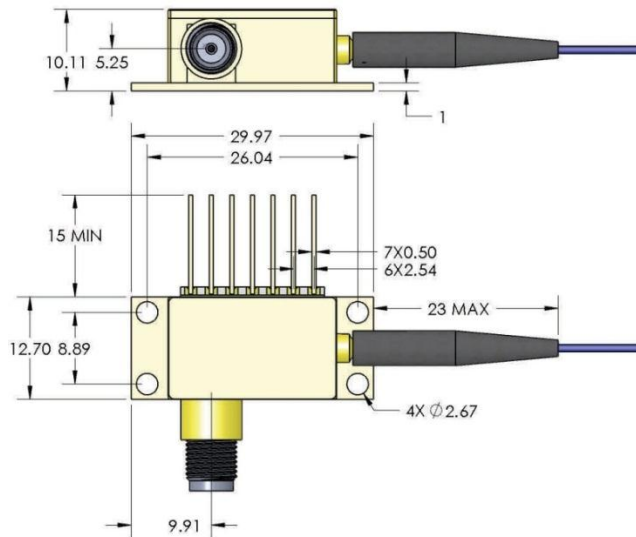
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## Typical Operating Characteristics



## Mechanical Drawing

All units in mm



## 1310nm/1550nm CWDM High-Bandwidth Laser

### Ordering Information

AA0701- ↑ ↑ ↑ ↑ ↑ ↑	FREQUE- ↑	POW- ↑	FIBuM- ↑	CON- ↑	50 ↑	Parameter	Option	Description
						Bias-T	50	50Ω Matched Bias-T
						Connector	NOC	No Connector
							FCA	FC/APC
							SCA	SC/APC
							LCA <sup>1</sup>	LC/APC, See Note 1 below
						Fiber & Buffer	SM250	Single Mode Fiber, 250um Buffer
							SM900	Single Mode Fiber, 900um Buffer
							PM250	PM Fiber, 250um Buffer
							PM900	PM Fiber, 900um Buffer
						Output Power	10	1530-1570nm
							18	1310nm
						Wave-length	FREQUE	For 1310nm: 228849
								For 1550nm: 193414
								For 1528-1570nm: Contact Factory
						Product Family	AA0701	High-Bandwidth DFB Laser

1. LCA connector only offered with SM900 fiber. Fiber length 530±20mm as measured from outside wall of package (snout end) to tip of ferrule on LCA connector.

The component complies with all applicable portions of 21 CFR 1040.10, 21 CFR 1010.2 and 21 CFR 1010.3. Since this is a component, it does not comply with all of the requirements contained in 21 CFR 1040.10 and 21 CFR 1040.11 for complete laser products.

For pricing and delivery information, please contact G & H direct at +1 781 275 75 01, [sales@em4inc.com](mailto:sales@em4inc.com).

The information published in this datasheet is believed to be accurate and reliable. G & H reserves the right to change without notice including but not limited to the design, specification, form, fit or function relating to the product herein.